

# Heterostructures of 2D materials and organic semiconductor nanolayers (H2O)

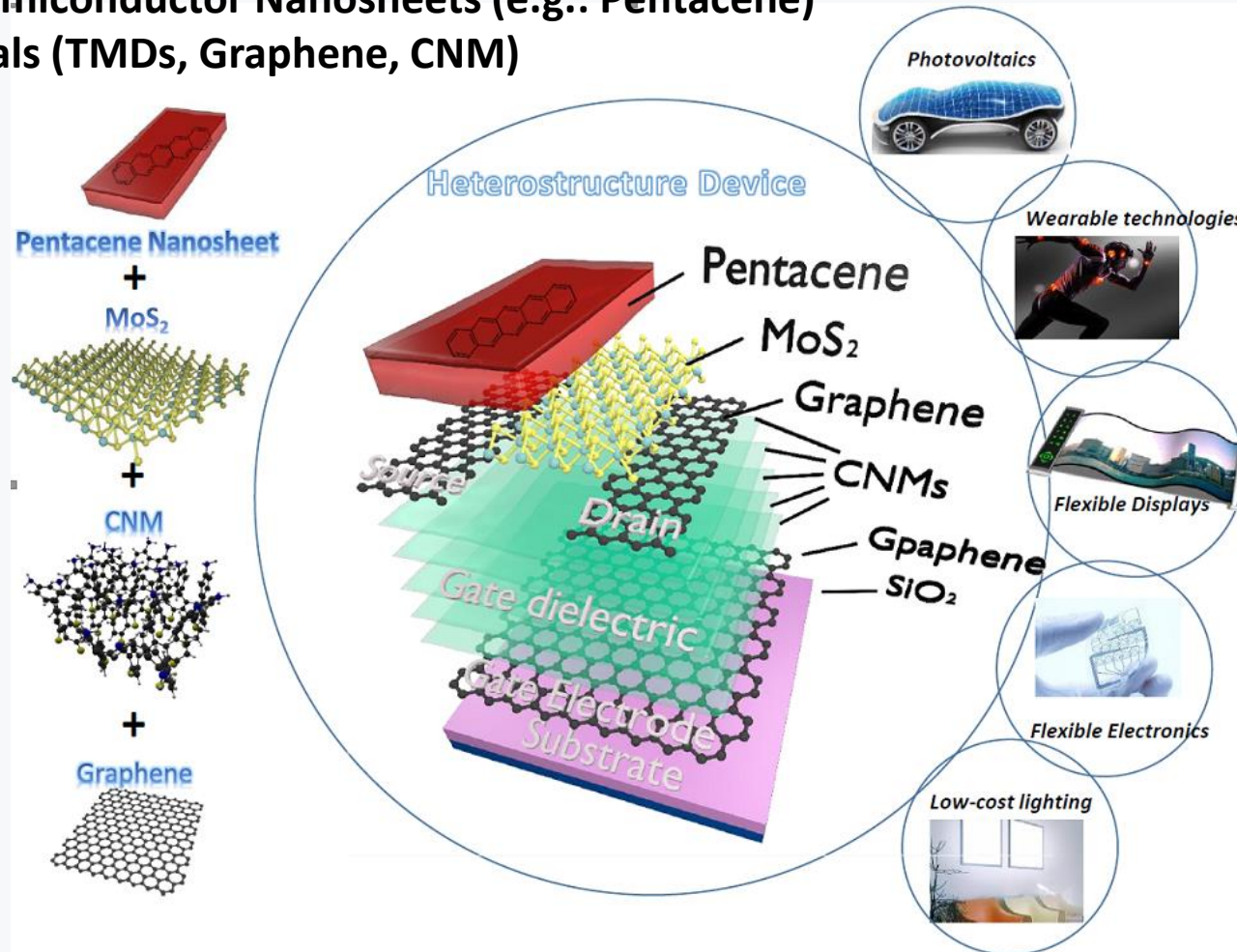
## Consortium:

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- Dr. Bert Nickel  
*Ludwig Maximilian University Munich, Germany*
- Prof. Sergey Kubatkin, Dr. Saroj Prasad Dash, Dr. Samuel Lara Avila  
*Chalmers University of Technology, Gothenburg, Sweden*
- Dr. Michel de Jong  
*University of Twente, Enschede, Netherlands*

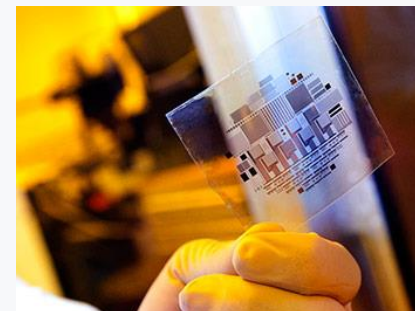


## van der Waals Heterostructures for Device Applications

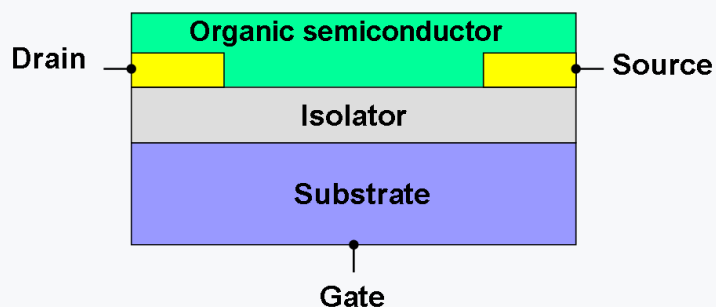
- Organic Semiconductor Nanosheets (e.g.: Pentacene)
- 2D materials (TMDs, Graphene, CNM)



- Low cost technology
- Compatibility with flexible plastic substrates
- Low temperature processing (60-120°C)
- Adjustable electronic characteristics by chemical tuning
- Compatible for solution monitoring and innovative applications such as biodegradable electronics

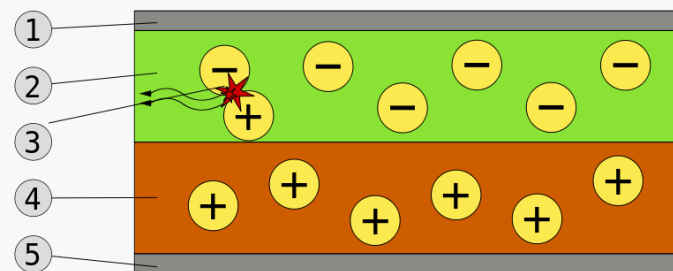


## Organic Field Effect Transistor (OFET)



- Charge carrier mobility in organic devices ranging from  $10^{-5}$  to  $1 \text{ cm}^2/\text{Vs}$

## Organic Light Emitting Diode (OLED)



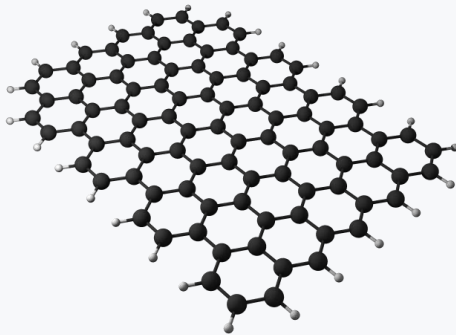
Schematic of a bilayer OLED: 1. Cathode (-), 2. Emissive Layer, 3. Emission of radiation, 4. Conductive Layer, 5. Anode (+)

- Commercialized technology, several products in market
- Companies Involved: BASF, Bayer, Philips, Merck, Novaled, Samsung, Sony, LG etc.
- Products: High Resolution Displays, Medical Devices, OLED Lighting Panels, Organic Solar Cells
- Market size of 45 Billion USD (2017)

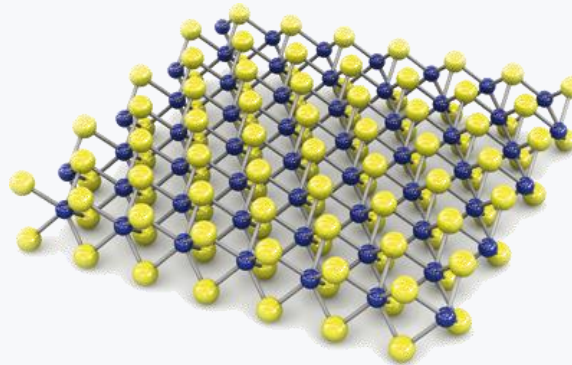


- Atomically thin single layer materials
- Available in metallic (graphene), semiconducting ( $\text{MoS}_2$ ,  $\text{WS}_2$ ,  $\text{WSe}_2$ ) and insulating (hBN, CNM) forms
- Flexible, transparent and light weight
- High charge carrier mobility and good optoelectronic characteristics
- Compatibility with plastic substrates
- Promising materials for emerging electronic, optoelectronic, energy and sensing device applications

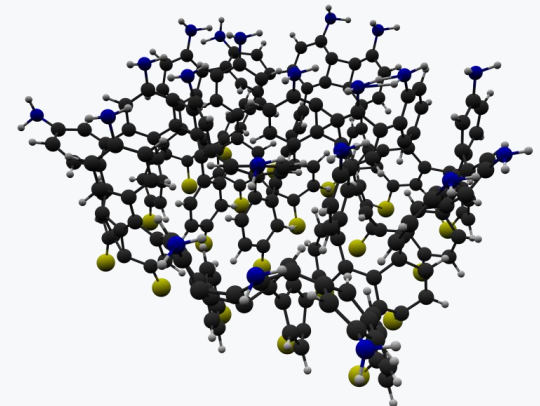
Graphene



TMD ( $\text{MoS}_2$ ,  $\text{WSe}_2$ ,  $\text{WS}_2$ )



Carbon Nanomembranes (CNM)



Carbon Nanomembranes, A. Turchanin and A. Götzhäuser, *Advanced Materials*, 28, 6075, 2017

Lateral Heterostructures of Two-dimensional Materials by Electron-beam Induced Stitching, A. Winter, A. George, A. Turchanin et al., *Carbon*, 128, 106, 2018

## Challenges in building 2D material-OSC vdW heterostructures

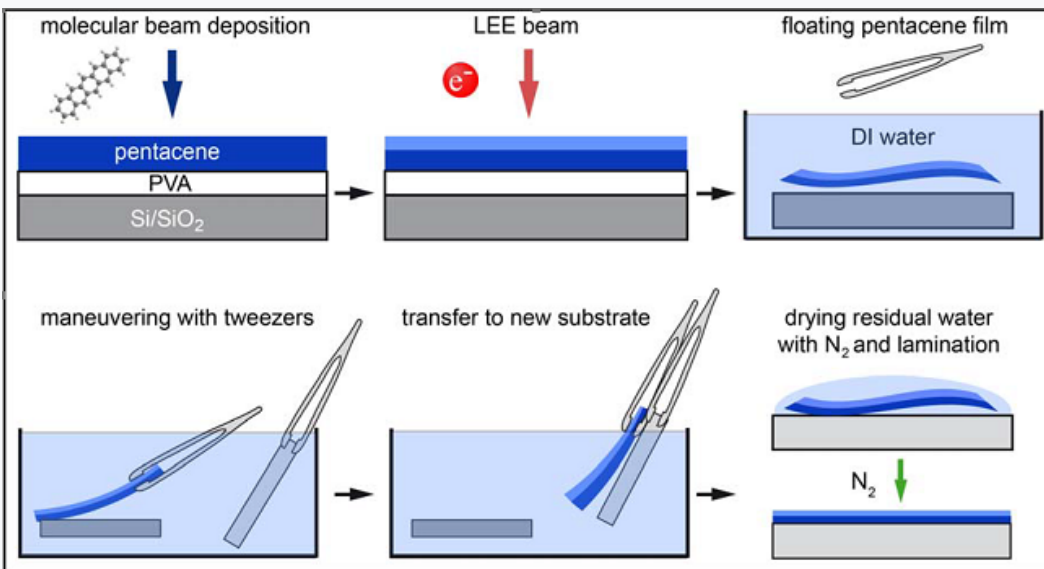
- Organic Semiconductor structural quality depends on the growth substrate and growth conditions.
- Direct deposition of OSC layers on 2D materials may result low structural quality (low crystallinity)
- Lower interfacial quality resulting in poor performance of the heterostructure devices
- **A viable solution : Transferrable organic semiconductor films to any arbitrary substrate**



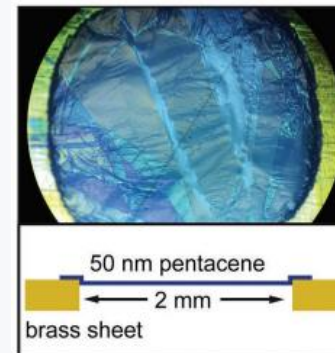
## Transferable OSC nanosheets

- Pentacene films (20-50 nm) can be grown with high crystallinity on polyvinyl alcohol (PVA) thin films.
- After the growth on PVA, the top molecular layers ( $\sim 5$  nm) are cross linked by e-beam irradiation.
- The crosslinked top layer stabilizes the film and become transferable to any arbitrary substrate without losing its structural/electronic quality.
- The technique can be extended to other OSC materials

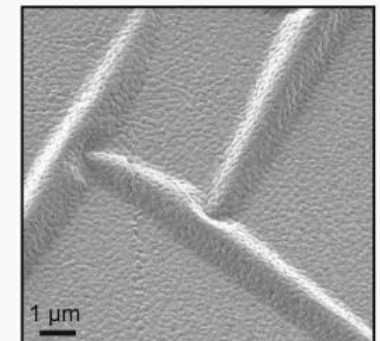
## Fabrication process of transferable OSC nanosheets



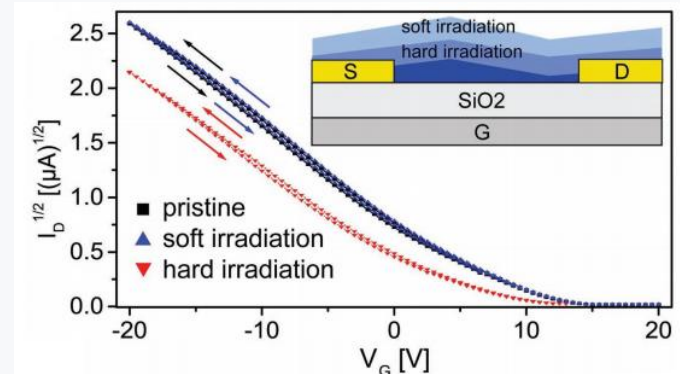
## Optical microscopy



## HIM image



## Transistor characteristics



**Transferable Organic Semiconductor Nanosheets for Application in Electronic Devices, S. J. Noever, A. Turchanin, B. Nickel et al., Advanced Materials, 23, 1606283, 2017**

| Friedrich Schiller University Jena, Germany  | Ludwig Maximilian University Munich, Germany   | Chalmers University of Technology, Sweden  | University of Twente, Enschede, Netherlands  |
|--|--|--|--|
| <b>Expertise:</b> 2D materials synthesis, characterization, nanofabrication, nano (opto)electronic devices   | <b>Expertise:</b> Organic semiconductors, photocurrent spectroscopy, organic (opto)electronic devices                    | <b>Expertise:</b> Advanced nanofabrication for complex device architectures, advanced transport measurements, device physics | <b>Expertise:</b> Synchrotron based spectroscopic studies of nanolayers and heterostructures |
| <b>Facilities:</b> CVD growth, E-beam processing, Optical microscopy, Raman Spectroscopy, XPS, HRTEM, SEM, cryogenic vacuum probe station, sensor testing, cleanroom nanofabrication | <b>Facilities:</b> Organic semiconductor processing, laser writing lithography, probe station, photocurrent spectroscopy | <b>Facilities:</b> Cleanroom nanofabrication, cryogenic vacuum probe station   | <b>Facilities:</b> ARPES, ARUPS, XPS   |



